IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Applicants:

Eliyahou Harari et al.

Assignee:

SanDisk Corporation

Title:

Flash EEPROM System

Application No.:

09/759,119

Filing Date:

January 1

Examiner:

Trong Phan

Group Art Unit:

2818

Docket No.:

M-10187-41C US

Conf. No.:

Unknown

San Francisco, California February 5, 2003

Commissioner for Patents

02/10/2003 LWDNDIH1 00000011 09759119

Washington, D. C. 20231

02 FC:1201

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SECOND VOLUNTARY AMENDMENT

Dear Sir:

Please amend the above referenced Application as follows:

In the Claims:

Please add the following new claims:

--80.(New) For an electrically alterable non-volatile multi-level semiconductor memory device including a plurality of non-volatile multi-level memory cells, each of the multi-level memory cells including a floating gate FET having a channel with electrically alterable voltage threshold value, the plurality of non-volatile multi-level memory cells being disposed in a matrix of rows and columns, channels of multi-level memory cells of a group of the plurality of non-volatile multi-level memory cells being coupled in parallel between a bit line and a reference potential, electrons being capable of being injected into the floating gate from the channel in each of the plurality of non-volatile multi-level memory cells, a method of operating the electrically alterable non-volatile multi-level semiconductor memory device, comprising:

setting a parameter of at least one non-volatile multi-level memory cell of the plurality of non-volatile multi-level memory cells to a state selected from a plurality of states

Application No.: 09/759,119 915218 v1

Express Mail No.: EV259164818US

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Trong Phan M-10187-41C US Filing Date:

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January 11, 2001

2818 Unknown TECHNOLOGY CENTER 2800

Dear Sir:

Transmitted herewith are the following documents in the above-identified application:

- (1) Return Receipt Postcard;
- (2) This Transmittal Letter;
- (3) Second Voluntary Amendment (34 pages);
- (4) Attachment Copy of U.S. Patent No. 6,344,998 B2; and
- (5) Check for \$534.00.

No additional fee is required.

The fee has been calculated as shown below:

CLAIMS AS AMENDED

Total Claims	Claims Remaining After Amendment		Highest No. Previously Paid For		Present Extra		Rate	Additi <u>Fee</u>	onal	I		
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